

Vishay General Semiconductor

Dual High-Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.50 \text{ V}$ at $I_F = 5 \text{ A}$



PRIMARY CHARACTERISTICS				
I _{F(AV)}	2 x 10 A			
V _{RRM}	60 V			
I _{FSM}	100 A			
V _F at I _F = 10 A	0.63 V			
T _J max.	150 °C			
Package	ITO-220AB			
Circuit configuration	Common cathode			

FEATURES

- Trench MOS Schottky technology
- · Low forward voltage drop, low power losses
- · High efficiency operation

• Solder bath temperature 275 °C max. 10 s, per JESD 22-B106

please see www.vishav.com/doc?99912

· Material categorization: for definitions of compliance

HALOGEN FREE

TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

MECHANICAL DATA

Case: ITO-220AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	VFT2060G	UNIT	
Maximum repetitive peak reverse voltage		V _{RRM}	60	V	
Maximum average forward rectified current (fig. 1)	per device	I _{F(AV)}	20	^	
	per diode		10	_ A	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load		I _{FSM}	100	А	
Voltage rate of change (rated V _R)		dV/dt	10 000	V/µs	
Isolation voltage from terminal to heatsink t = 1 min		V _{AC}	1500	V	
Operating junction and storage temperature range		T _J , T _{STG}	-55 to +150	°C	



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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Instantaneous forward voltage per diode	I _F = 5.0 A	T _A = 25 °C	V _F ⁽¹⁾	0.58	=	V	
	I _F = 10 A			0.69	0.90		
	$I_F = 5.0 \text{ A}$	T _A = 125 °C		0.50	-		
	I _F = 10 A			0.63	0.84		
Reverse current per diode	$V_R = 60 \text{ V}$ $T_A = 25 \text{ °C}$ $T_A = 125 \text{ °C}$	T _A = 25 °C	I _R ⁽²⁾	-	700	μΑ	
		'R ⁽⁻⁾	8.0	25	mA		

Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)				
PARAMETER		SYMBOL	VFT2060G	UNIT
Typical thermal resistance	per diode	- R _{θJC}	7.0	°C/W
	per device		5.2	C/VV

ORDERING INFORMATION (Example)							
PACKAGE PREFERRED P/N		UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
ITO-220AB	VFT2060G-M3/4W	1.75	4W	50/tube	Tube		

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

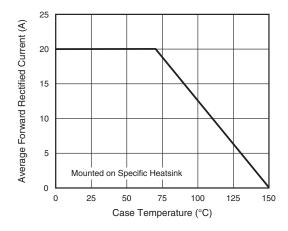


Fig. 1 - Maximum Forward Current Derating Curve

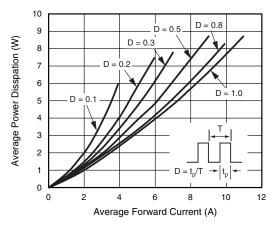


Fig. 2 - Forward Power Dissipation Characteristics



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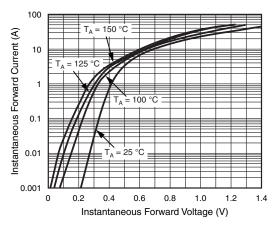


Fig. 3 - Typical Instantaneous Forward Characteristics

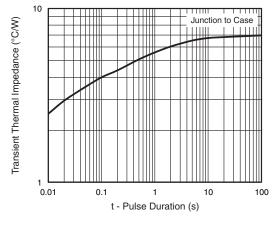


Fig. 5 - Typical Transient Thermal Impedance

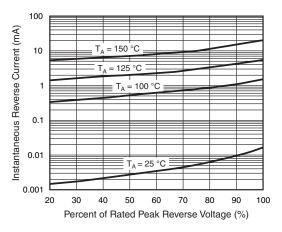


Fig. 4 - Typical Reverse Characteristics

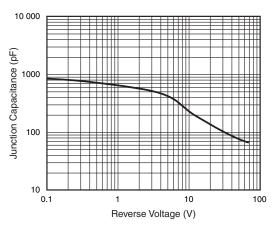
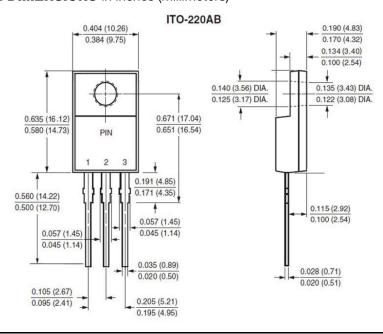


Fig. 6 - Typical Junction Capacitance

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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